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Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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MMST2222A

NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMST2907A)
- Ultra-Small Surface Mount Package
- Also Available in Lead Free Version

Mechanical Data

- Case: SOT-323, Molded Plastic
- Case Material UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 4, on Page 2
- Terminal Connections: See Diagram
- Marking (See Page 2): K3P
- Ordering & Date Code Information: See Page 2
- Weight: 0.006 grams (approx.)



SOT-323							
Dim	Min	Max					
Α	0.25	0.40					
В	1.15	1.35					
С	2.00	2.20					
D	0.65 Nominal						
E	0.30	0.40					
G	1.20	1.40					
н	1.80	2.20					
J	0.0	0.10					
к	0.90	1.00					
L	0.25	0.40					
м	0.10	0.18					
α	0°	8°					
All Dimensions in mm							

Maximum Ratings @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	MMST2222A	Unit		
Collector-Base Voltage	V _{CBO}	75	V		
Collector-Emitter Voltage	V _{CEO}	40	V		
Emitter-Base Voltage	V _{EBO}	6.0	V		
Collector Current - Continuous (Note 1)	Ic	600	mA		
Power Dissipation (Note 1)	Pd	200	mW		
Thermal Resistance, Junction to Ambient (Note 1)	R _{θJA}	625	°C/W		
Operating and Storage and Temperature Range	T _j , T _{STG}	-55 to +150	٥C		

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Electrical Characteristics @ T _A = 25°C unless otherwise specified								
Characteristic	Symbol	Min	Мах	Unit	Test Condition			
OFF CHARACTERISTICS (Note 2)								
Collector-Base Breakdown Voltage	V _{(BR)CBO}	75	_	V	$I_{C} = 10 \mu A, I_{E} = 0$			
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	40	_	V	$I_C = 10 \text{mA}, I_B = 0$			
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0		V	$I_E = 10 \mu A, \ I_C = 0$			
Collector Cutoff Current	I _{СВО}	_	10	nA μA				
Collector Cutoff Current	ICEX	_	10	nA	$V_{CE}=60V, V_{EB(OFF)}=3.0V$			
Emitter Cutoff Current	I _{EBO}	—	10	nA	$V_{EB} = 3.0V, I_{C} = 0$			
Base Cutoff Current	I _{BL}		20	nA	$V_{CE} = 60V, \ V_{EB(OFF)} = 3.0V$			
ON CHARACTERISTICS (Note 2)								
DC Current Gain	h _{FE}	35 50 75 100 40 50 35	 300 	_	$ \begin{array}{ll} I_C = & 100 \mu A, V_{CE} = & 10V \\ I_C = & 1.0mA, V_{CE} = & 10V \\ I_C = & 10mA, V_{CE} = & 10V \\ I_C = & 150mA, V_{CE} = & 10V \\ I_C = & 500mA, V_{CE} = & 10V \\ I_C = & 10mA, V_{CE} = & 10V, T_A = -55^{\circ}C \\ I_C = & 150mA, V_{CE} = & 1.0V \\ \end{array} $			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.3 1.0	V	$\label{eq:lc} \begin{array}{l} I_C = 150 \text{mA}, \ I_B = 15 \text{mA} \\ I_C = 500 \text{mA}, \ I_B = 50 \text{mA} \end{array}$			
Base- Emitter Saturation Voltage	V _{BE(SAT)}	0.6	1.2 2.0	V	$\label{eq:lc} \begin{array}{l} I_C = 150 m A, \ I_B = 15 m A \\ I_C = 500 m A, \ I_B = 50 m A \end{array}$			
SMALL SIGNAL CHARACTERISTICS								
Output Capacitance	C _{obo}		8	pF	$V_{CB} = 10V, f = 1.0MHz, I_E = 0$			
Input Capacitance	C _{ibo}	_	25	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$			
Current Gain-Bandwidth Product	f _T	300	_	MHz	$\label{eq:Vce} \begin{array}{l} V_{CE} = 20V, \ I_C = 20mA, \\ f = 100MHz \end{array}$			
Noise Figure	NF	—	4.0	dB	$\label{eq:Vce} \begin{array}{l} V_{CE} = 10V, \ I_C = 100 \mu A, \\ R_S = 1.0 k \Omega, \ f = 1.0 k Hz \end{array}$			
SWITCHING CHARACTERISTICS								
Delay Time		_	10	ns	$V_{CC} = 30V, I_{C} = 150mA,$			
Rise Time	tr	_	25	ns	$V_{BE(off)} = -0.5V, I_{B1} = 15mA$			
Storage Time	Storage Time t _s -			ns	$V_{CC} = 30V, I_C = 150mA,$			
Fall Time	t _f		60	ns	$I_{B1} = I_{B2} = 15mA$			

Ordering Information (Note 3)

Device	Packaging	Shipping			
MMST2222A-7	SOT-323	3000/Tape & Reel			

Notes: 2. Short duration test pulse used to minimize self-heating effect.

For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.
For Lead Free version (with Lead Free terminal finish) part number, please add "-F" suffix to part number above. Example: MMST2222A-7-F.

Marking Information

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K3P K3P = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 Y = Year ex: N = 2002 M = Month ex: 9 = September												
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	J	K	L	М	Ν	Р	R	S	Т	U	V	W
Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





Fig. 6 Base Emitter Voltage vs. Collector Current

